

# 2-Output LVDS Networking Clock Generator

### **Features**

- → Two differential LVDS output pairs
- → Selectable crystal oscillator interface or LVCMOS/LVTTL single-ended clock input
- → Supports the following output frequencies: 62.5MHz, 125MHz, 156.25MHz
- → RMS phase jitter @ 156.25MHz, using a 25MHz crystal (1.875MHz 20MHz): 0.2ps (typical)
- → RMS phase jitter @ 156.25MHz, using a 25MHz crystal (12kHz 20MHz): 0.32ps (typical)
- → Full 3.3V or 2.5V supply modes
- → Commercial and industrial ambient operating temperature
- → Available in lead-free package: 20-TSSOP

## **Description**

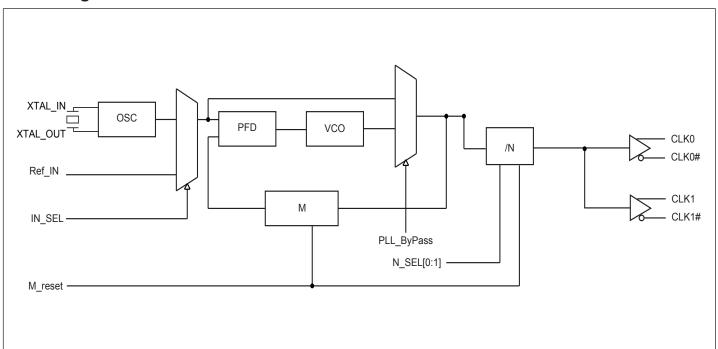
The PI6LC48L0201 is a 2-output LVDS synthesizer optimized to generate Ethernet reference clock frequencies and is a member of Pericom's HiFlex family of high performance clock solutions. Using a 25MHz crystal, the most popular Ethernet frequencies can be generated based on the settings of 2 frequency select pins.

The PI6LC48L0201 uses Pericom's proprietary low phase noise PLL technology to achieve ultra low phase jitter, so it is ideal for Ethernet interface in all kind of systems.

# **Applications**

→ Networking systems

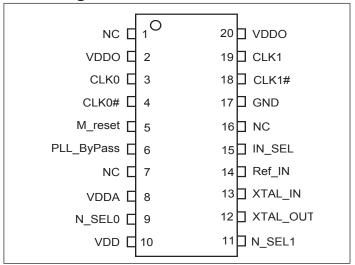
# **Block Diagram**



13-0115 1 www.pericom.com PI6LC48L0201 Rev. A 07/23/2013



# **Pin Configuration**



## **Pinout Table**

	moor rable					
Pin No.	Pin Name	I/O Type		Description		
1, 7, 16	NC			No connection		
2, 20	VDDO	Power	-	Output Power Supply		
3,4	CLK0, CLK0#	Output	-	LVDS Output clock 0		
5	M_reset	Input	Pull-down	Master reset. "1", CLK0CLK1 go to "low", CLK0#/CLK1# go to "high"; "0" outputs are enabled		
6	PLL_ByPass	Input	Pull-down	PLL bypass select. "0" PLL is enabled, "1" PLL is bypassed		
8	VDDA	Power	-	Analog Power Supply		
9, 11	N_SEL0, N_SEL1	Input	Pull-down	Output frequency select		
10	VDD	Power	-	Core Power Supply		
12, 13	XTAL_OUT, XTAL_IN	Crystal	-	Crystal input and output		
14	Ref_IN	Input	Pull-down	CMOS reference clock input		
15	IN_SEL	Input	Pull-down	"0" selects Crystal, "1" selects reference input		
17	GND	Ground	-	Ground		
18, 19	CLK1#, CLK1	Output	-	LVDS Output clock 1		



**Output Frequency Selection Table** 

Xtal Frequency	N_SEL1 N_SEL0	Output Frequency
	00	156.25
25	01	125
25	10	62.5
	11	Reserved

**Typical Crystal Requirement** 

/1 / 1			1	
Parameter	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental		
Frequency	22.4	25	27.2	MHz
Equivalent Series Resistance (ESR)			50	Ω
Shunt Capacitance			7	pF
Drive Level			1	mW

# **Recommended Crystal Specification**

Pericom recommends:

- a) FL2500047, SMD 3.2x2.5(4P), 25MHz, CL=18pF, +/-20ppm, http://www.pericom.com/pdf/datasheets/se/FL.pdf
- b) FY2500091, SMD 5x3.2(4P), 25MHz, CL=18pF, +/-30ppm, http://www.pericom.com/pdf/datasheets/se/FY\_F9.pdf



## Maximum Ratings (Over operating free-air temperature range)

Storage Temperature65°C to+155°C
Ambient Temperature with Power Applied40°C to+85°C
3.3V Analog Supply Voltage0.5 to +3.6V
ESD Protection (HBM)

#### Note

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## **DC Electrical Characteristics**

**Power Supply DC Characterisitcs,** (T<sub>A</sub> = -40°C to 85°C)

Symbol	Parameter	Condition	Min	Тур	Max	Units	
$\begin{array}{c} V_{DD,} \\ V_{DDA,} \ V_{DDO} \end{array}$	Core Supply Voltage		3.135	3.3	3.465	V	
$\begin{matrix} V_{DD,} \\ V_{DDA,} \ V_{DDO} \end{matrix}$	Analog Supply Voltage		2.375	2.5	2.625	V	
т	Power Supply Current	$V_{\rm DD} = V_{\rm DDA} = V_{\rm DDO} = 3.3V + /-5\%$			105	mA	
$I_{ m DD}$		$V_{\rm DD} = V_{\rm DDA} = V_{\rm DDO} = 2.5 V + /-5\%$			98		
т	Analog Supply Current	$V_{DD} = V_{DDA} = V_{DDO} = 3.3V + /-5\%$			26	A	
$I_{DDA}$	Analog Supply Current	$V_{\rm DD} = V_{\rm DDA} = V_{\rm DDO} = 2.5 V + /-5\%$			26	mA	
T	Outmut Comply Comment	$V_{\rm DD} = V_{\rm DDA} = V_{\rm DDO} = 3.3V + /-5\%$			55	mA	
$I_{DDO}$	Output Supply Current	$V_{\rm DD} = V_{\rm DDA} = V_{\rm DDO} = 2.5 V + /-5\%$			55		

## **LVCMOS/LVTTL DC Characterisitcs,** $(T_A = -40$ °C to 85°C)

Symbol	Parameter	Condition	Min	Тур	Max	Units
3.7	Innet II: al. Valta an	V <sub>DD</sub> = 3.3 V +/- 5%	2		V <sub>DD</sub> + 0.3	V
$V_{IH}$	Input High Voltage	V <sub>DD</sub> = 2.5 V +/- 5%	1.7		V <sub>DD</sub> + 0.3	V
37	Input Low Voltage	V <sub>DD</sub> = 3.3 V +/- 5%	-0.3		0.8	V
$ m V_{IL}$	Input Low Voltage	V <sub>DD</sub> = 2.5 V +/- 5%	-0.3		0.7	V
I <sub>IH</sub>	Input High Current	$\begin{aligned} & \text{M\_reset, PLL\_ByPass, N\_} \\ & \text{SEL[0:1], IN\_SEL, Ref\_IN} \\ & V_{\text{DD}} = \text{VIN} = 3.465 \text{V} \end{aligned}$			150	μΑ
I <sub>IL</sub>	Input Low Current	$\begin{aligned} & \text{M\_reset, PLL\_ByPass, N\_} \\ & \text{SEL[0:1], IN\_SEL, Ref\_IN} \\ & V_{\text{DD}} = 3.465\text{V}, V_{\text{IN}} = 0\text{V} \end{aligned}$	-5			μΑ

### **Pin Characterisitcs**

Symbol	Parameter	Condition	Min	Typ	Max	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLDOWNN</sub>	Pull down resistor			51		kΩ



# **LVDS DC Characterisitcs,** $(T_A = -40 \, ^{\circ}\text{C} \text{ to } 85 \, ^{\circ}\text{C})$

Symbol	Parameter	Condition	Min	Тур	Max	Units	
3.7	Differential Output Voltage	$V_{_{ m DD}} = 3.3  m V$	247		454	***	
$V_{\mathrm{OD}}$		$V_{_{ m DD}} = 2.5  m V$	247		454	mV	
$\Delta V_{\mathrm{OD}}$	Change of V <sub>OD</sub>	$V_{_{ m DD}} = 3.5  m V$		50		3.7	
		$V_{_{ m DD}} = 2.5  m V$		50		mV	
***	Output Offset Voltage	$V_{DD} = 3.3V$	1.125		1.375	V	
V <sub>OS</sub>		$V_{_{ m DD}} = 2.5  m V$	1.125		1.375	V	
	Change of Vos	$V_{_{ m DD}} = 3.5  m V$		50			
$\Delta V_{OS}$		$V_{DD} = 2.5V$		50		mV	

# AC Electrical Characteristics, $(T_A = -40 \, ^{\circ} C \ to \ 85 \, ^{\circ} C)$

Symbol	Parameter	Condition	Min.	Тур.	Max	Units
	N_SEL[1:0] = 00 140			170	MHz	
fout	Output Frequency	N_SEL[1:0] = 01	112		136	MHz
		$N_{SEL[1:0]} = 10$	56		68	MHz
$t_{ m sk(o)}$	Output Skew <sup>(1, 3)</sup>	Outputs @ same loading		50		ps
		156.25MHz, (1.875MHz - 20MHz)		0.2		ps
	RMS Phase Jitter, (Random) <sup>(2)</sup>	156.25MHz, (12kHz - 20MHz)		0.32		ps
		125MHz, (1.875MHz - 20MHz)		0.2		ps
$t_{ m jit}(\varnothing)$		125MHz, (12kHz - 20MHz)		0.31		ps
		62.5MHz, (1.875MHz - 20MHz)		0.4		ps
		62.5MHz, (12kHz - 20MHz)		0.5		ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%			400	ps
odc	Output Duty Cycle		48		52	%

### Note:

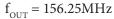
 $<sup>\</sup>textbf{1.} \ Defined \ as \ skew \ within \ a \ bank \ of \ outputs \ at \ the \ same \ supply \ voltage \ and \ with \ equal \ load \ conditions. \ Measured \ at \ the \ differential \ cross \ points.$ 

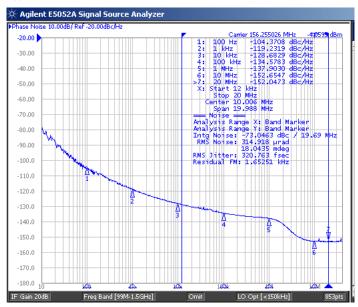
 $<sup>{\</sup>bf 2.}$  Please refer to the Phase Noise Plots.

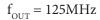
 $<sup>{\</sup>bf 3.}$  This parameter is defined in accordance with JEDEC Standard 65.

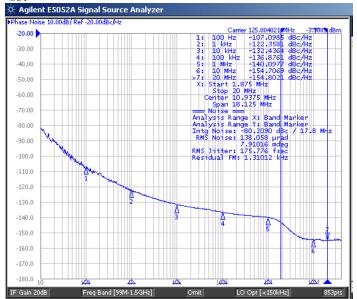


## **Phase Noise Plots**

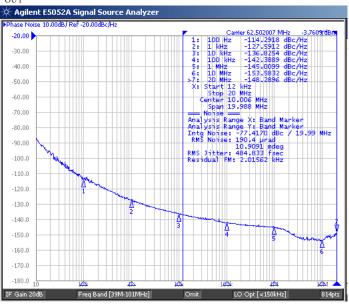






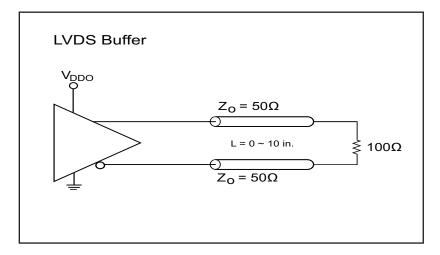


# $f_{OUT} = 62.5MHz$



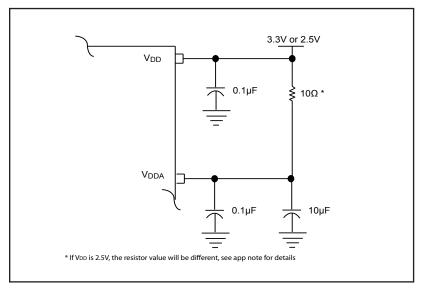


### **LVDS Test Circuit**



# **Power Supply Filtering Techniques**

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The PI6LC48L0201 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$ ,  $V_{DDA}$  and  $V_{DDO}$  should be individually connected to the power supply plane through vias, and  $0.1\mu F$  bypass capacitors should be used for each pin. Figure below illustrates this for a generic  $V_{DD}$  pin and also shows that  $V_{DDA}$  requires that an additional  $10\Omega$  resistor along with a  $10\mu F$  bypass capacitor be connected to the  $V_{DDA}$  pin.





# **Recommendations for Unused Input and Output Pins**

### **Inputs:**

Crystal Inputs:

For applications not requiring the use of the crystal oscillator input, both XTAL\_IN and XTAL\_OUT can be left floating. A  $1k\Omega$  resistor can be tied from XTAL\_IN to ground for additional protection.

### Ref\_IN Input:

For applications not requiring the use of the clock, it can be left floating. A  $1k\Omega$  resistor tied from the Ref\_IN to ground can provide additional protection.

### LVCMOS Control Pins:

All control pins have internal pulldowns; A  $1k\Omega$  resistor tied from each control pin to ground can provide additional protection.

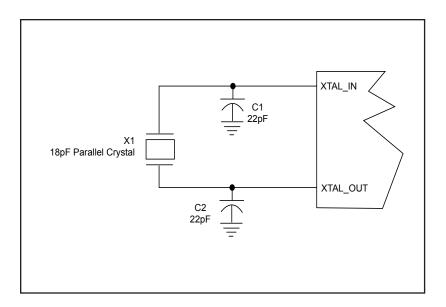
### **Outputs:**

LVDS Outputs:

All unused LVDS output pairs can be either left floating or terminated with  $100\Omega$  across. If they are left floating, we recommend that there is no trace attached.

# **Crystal Input Interface**

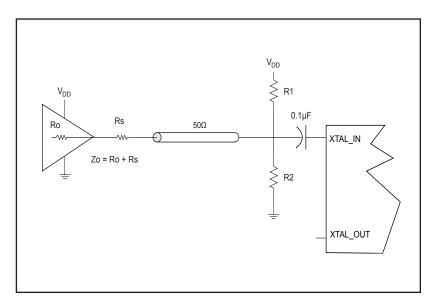
The clock generator has been characterized with 18pF parallel resonant crystals. The capacitor values shown in the figure below were determined using a 25MHz, 18pF parallel resonant crystal and were chosen to minimize the ppm error.





### **LVCMOS** to XTAL Interface

The XTAL\_IN input can accept a single-ended LVCMOS signal through an AC coupling capacitor. A general interface diagram is shown in the figure below. The XTAL\_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVCMOS signals, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output impedance of the driver (Ro) plus the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of the two ways. First, R1 and R2 in parallel should equal the transmission line empedance. For most  $50\Omega$  applications, R1 and R2 can be  $100\Omega$ . This can also be accomplished by removing R1 and making R2  $50\Omega$ . By overdriving the crystal oscillator, the device will be functional, but note, the device performance is quaranteed by using a quartz crystal.

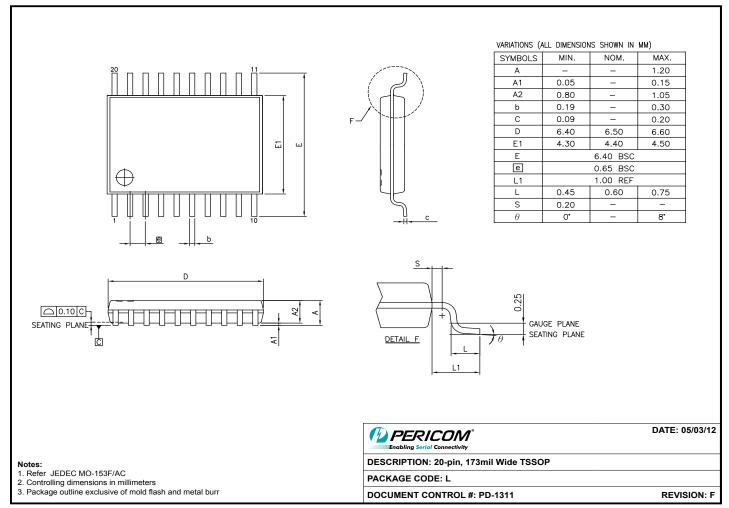


### **Thermal Information**

Symbol	Description	Condition	
$\Theta_{_{ m JA}}$	Junction-to-ambient thermal resistance	Still air	84.0 °C/W
$\Theta_{ m JC}$	Junction-to-case thermal resistance		17.0 °C/W



# Packaging Mechanical: 20-Contact TSSOP (L)



12-0373

# **Ordering Information**

Ordering Code	Packaging Type	Package Description	Operating Temperature
PI6LC48L0201LE	L	Pb-free & Green, 20-pin TSSOP	Commercial
PI6LC48L0201LIE	L	Pb-free & Green, 20-pin TSSOP	Industrial

#### Notes

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- "E" denotes Pb-free and Green
- Adding an "X" at the end of the ordering code denotes tape and reel packaging

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